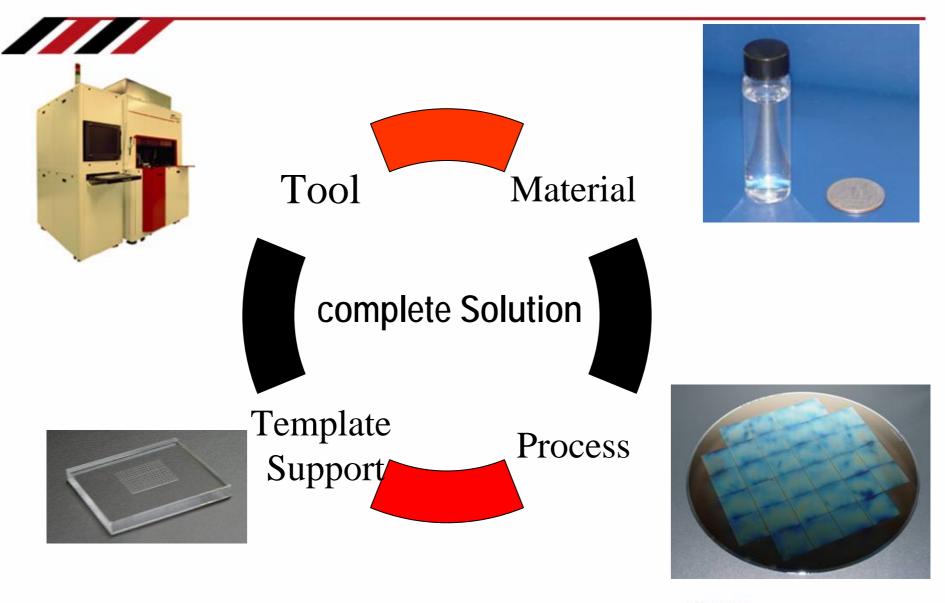


Molecular Imprints

The Impact of Step and Flash Imprint Lithography for Nano-Manufacturing in Emerging Market Applications

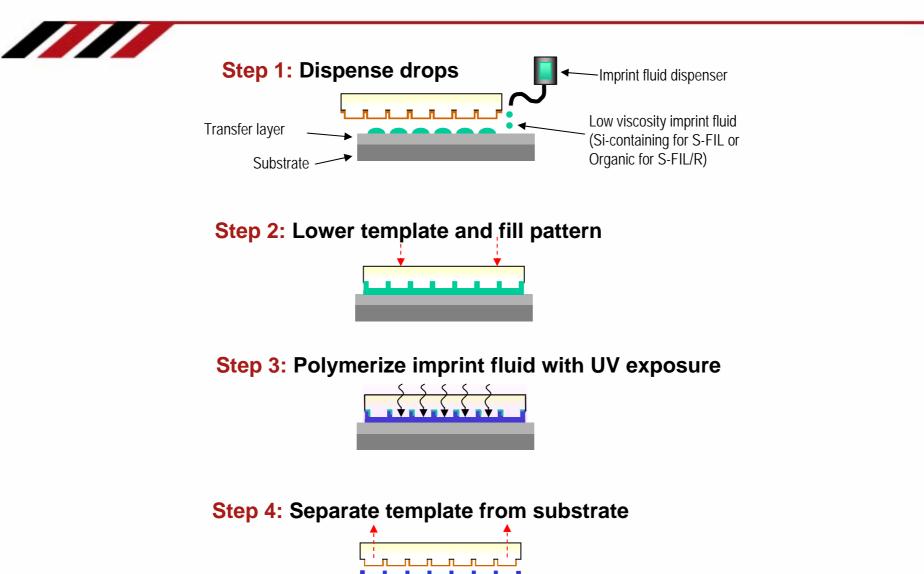
Pascal Gubbini, Niyaz Khusnatdinov, Gerard Schmid, Nick Stacey, Ian McMackin, Jin Choi, Ecron Thompson, Rob Hershey, Dwayne Labrake Litho 2006 Marseille

Molecular Imprints Solution





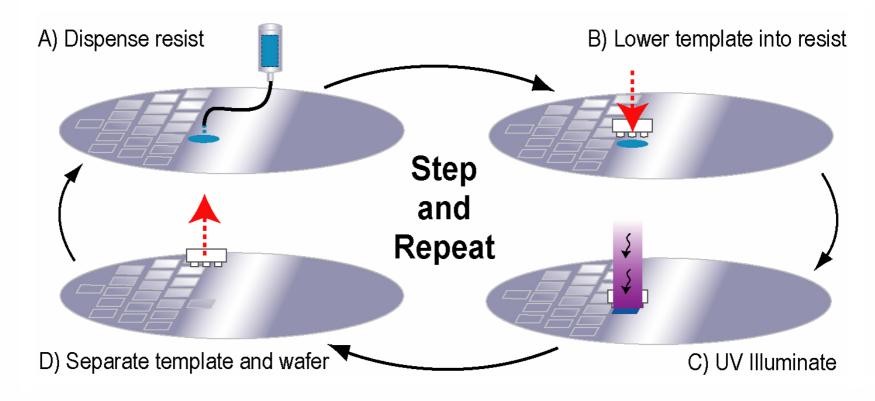
Step & Flash Imprint Lithography (S-FIL & S-FIL/R™)





Process on wafer scale

Step and Flash Imprint Lithography (S-FIL[™])

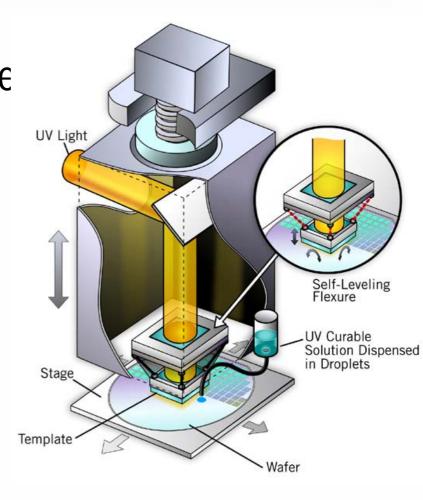


Room temperature Low pressure



Step & Flash Imprint Lithography (S-FIL & S-FIL/R™)

- Field-to-field fluid dispense
 Low viscosity fluid (1 to 5 cps)
 Liquid volume match template pattern
 - Room temperature
 Low pressure (< 0.5 psi)
 No contact between template and substrate





Imprio Products





- Overlay: 1 um, 1s
- Up to 200 mm
- > 25x25mm field





- Overlay: 500 nm, 3s
- Up to 200 mm
- > 25x25mm field
- Automatic Field Alignment



- Overlay: 50 nm, 3s including magnification correction
- Up to 300 mm
- > 26x33mm field
- Fully Automatic cassette to cassette wafer handling.



Sub 100nm Lithography techniques

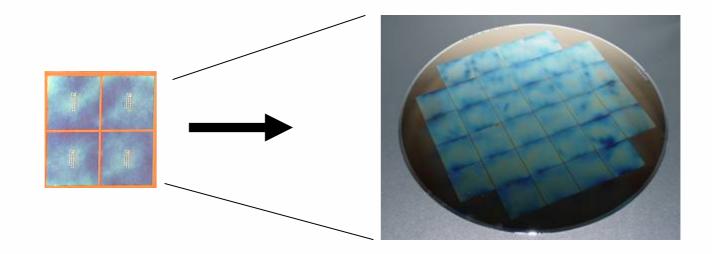
	Optical Litho	EBL	Nano- imprint
Low Defect Process	\checkmark	\checkmark	\checkmark
Pattern Independence	\checkmark		\checkmark
Precision Overlay Alignment	\checkmark	\checkmark	\checkmark
Handles Fragile Substrates	\checkmark	\checkmark	\checkmark
High resolution		\checkmark	\checkmark
Reliable processes	\checkmark	\checkmark	\checkmark
Wafer scale uniformity	\checkmark	\checkmark	\checkmark
Copies Critical Dimensions Exactly Excellent LER and CD control			\checkmark
3-D Patterning of Functional Materials			\checkmark
Low Cost of ownership for sub-500 nm resolution patterning			\checkmark



Complementary Techniques

E-Beam: can write patterns down to 8nm resolution but at slow speed

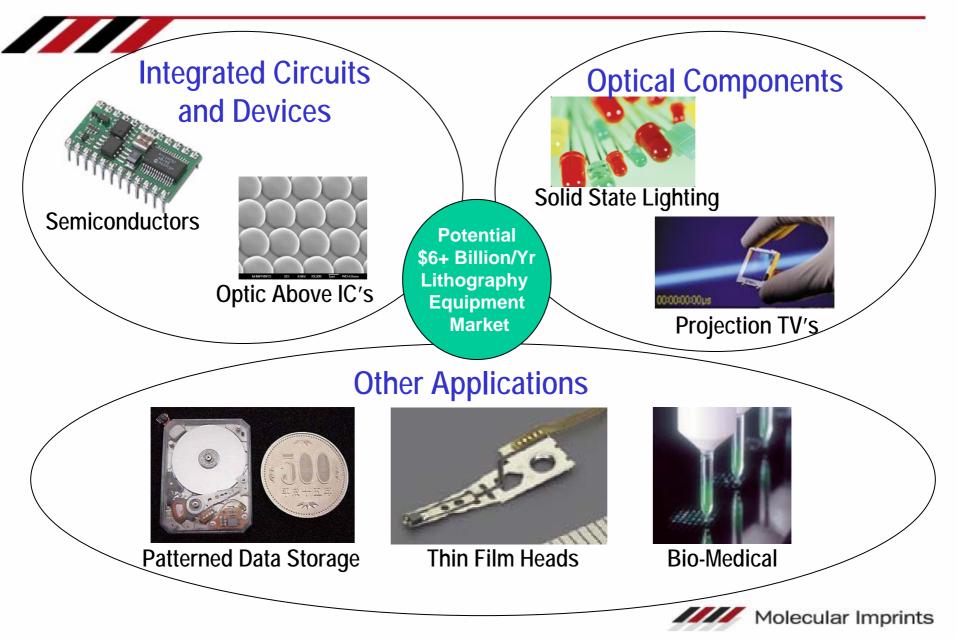
Nanoimprint pattern a full wafer in minutes.



Nanoimprint Lithography : The E-Beam Amplifier

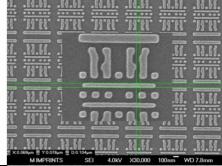


S-FIL Nanoscale Market Opportunities



Industrial Applications Company Focus

Advanced Lithography



0.0000.000

LED Light Extraction





Patterned Media



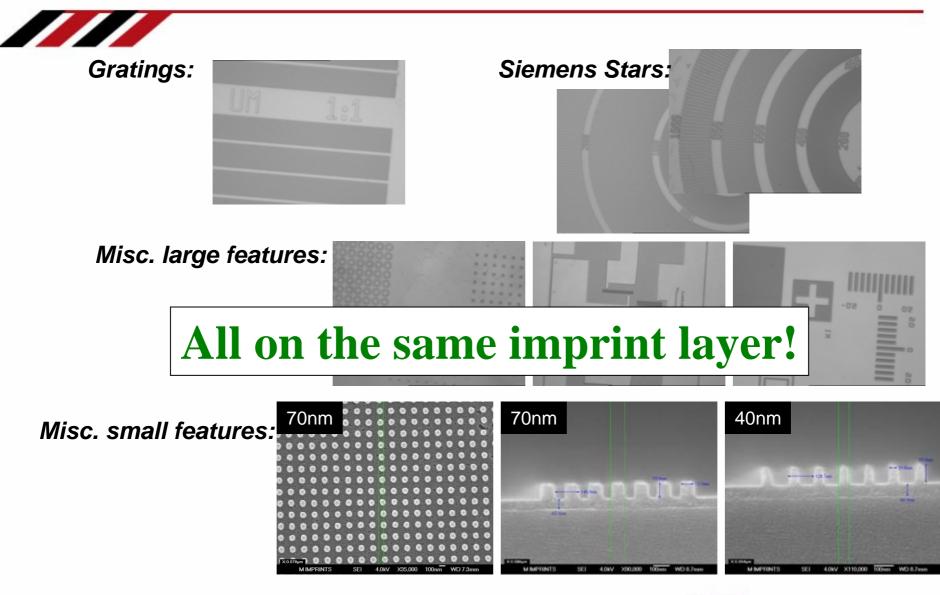




Molecular Imprints

Emerging Market Applications

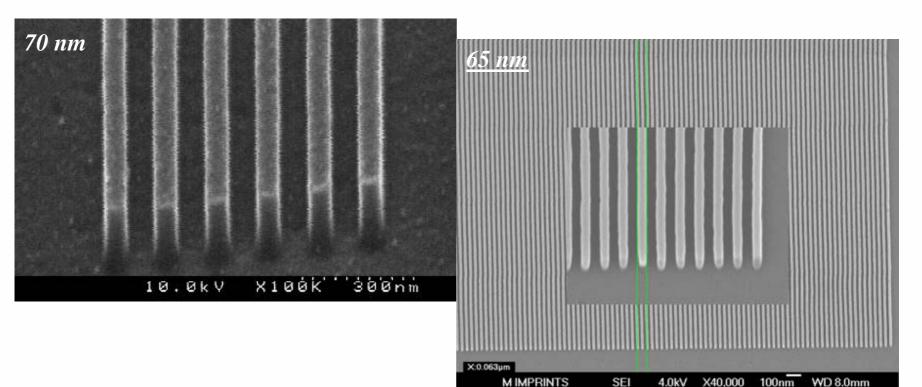
2D Imprint Capabilities: >100um to <100nm





Application: Wire Grid Polarizers

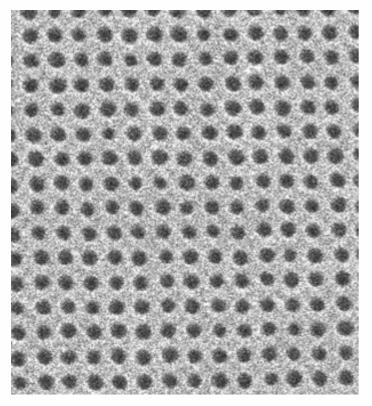
- Goal: Fabricate an aluminum wire grid polarizer on a glass substrate to increase the polarizer's extinction ratio for TV projectors
- Approach: Imprint sub-70nm lines/spaces nano-grating structure
- Experimental Results: >99.5% extinction ratio

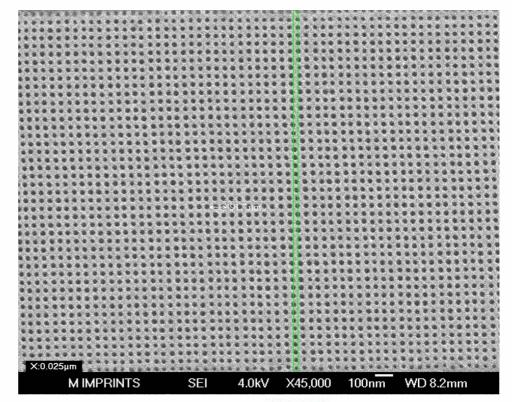


Molecular Imprints

Application: High Density Storage

- Goal: Implement bit patterning on memory disk substrates to increase the memory density of Hard Disk Drives (HDD).
- Approach: Imprint 25nm hyper-dense contacts (45nm pitch)
- Experimental Results: >300 Gb/in² capable patterned media

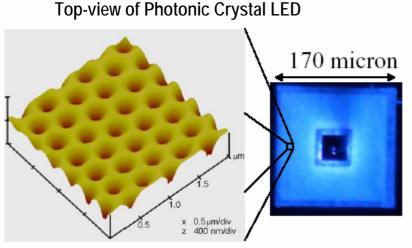


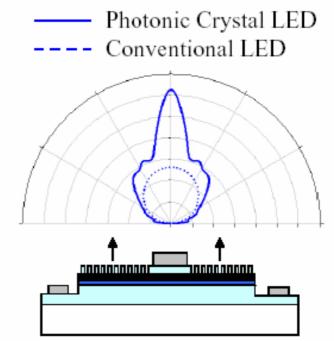


Molecular Imprints

Higher Brightness LEDs using Photonic Crystals

- Goal: High brightness photonic crystal LED (PXLED)
- Approach: Photonic crystal patterned on top of GaN layer
- Experimental Results: Total light extraction gain of ~1.5 times relative to planar LED's, optimize light directionality





Light intensity vs. angle. The Photonic Crystal LED's light emission is narrow.

250nm holes etched into GaN Source: Lumileds, *Applied Physics Letters*, May 10, 2004





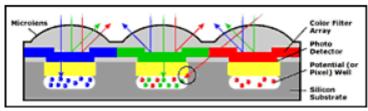
Molecular Imprints

Micro-lenses for Image Sensors

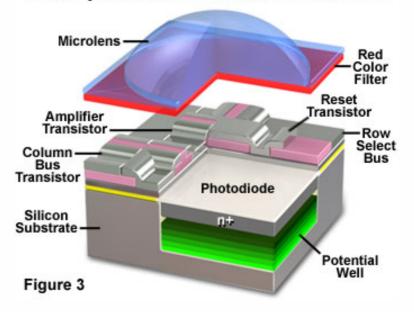
Image Sensor Challenges

Light gathering

- Shrinking light collection zone
- Getting correct focal length and alignment
- Fill factor of Lens relative to pixel
- Reduce Optical Crosstalk

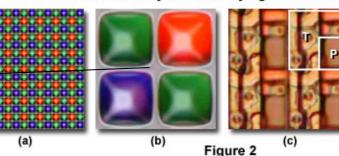


Anatomy of the Active Pixel Sensor Photodiode



Bayer Color Filter Mosaic Array and Underlying Photodiodes

Goal: eliminate dead space between lenses.

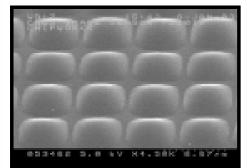


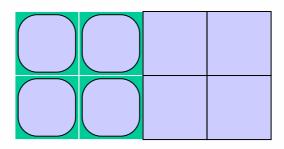


Value Proposition

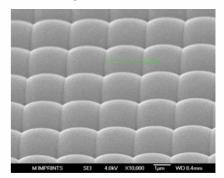
- Driven by pixel size shrinkage
 - 2 3 um Pixel 130nm CMOS
 - 1.2-1.8 um Pixel 90nm CMOS
- Value driven by reduction in space between lenses

Reflow Lens





Imprinted Lens





Grayscale Templates: Micro Lenses at MII

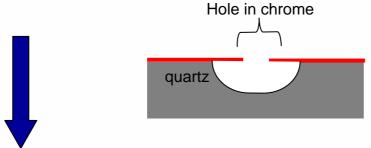


- Template fabrication
- Imprint Material
- Imprint Process



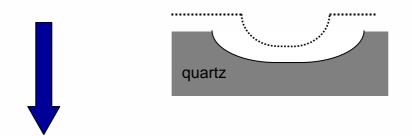
Grayscale Template Fabrication

1. Use E-beam or laser PG to define holes in chrome-on-quartz photomask



First etch – defines lens depth

2. Use wet etching through holes to create isotropic features in quartz

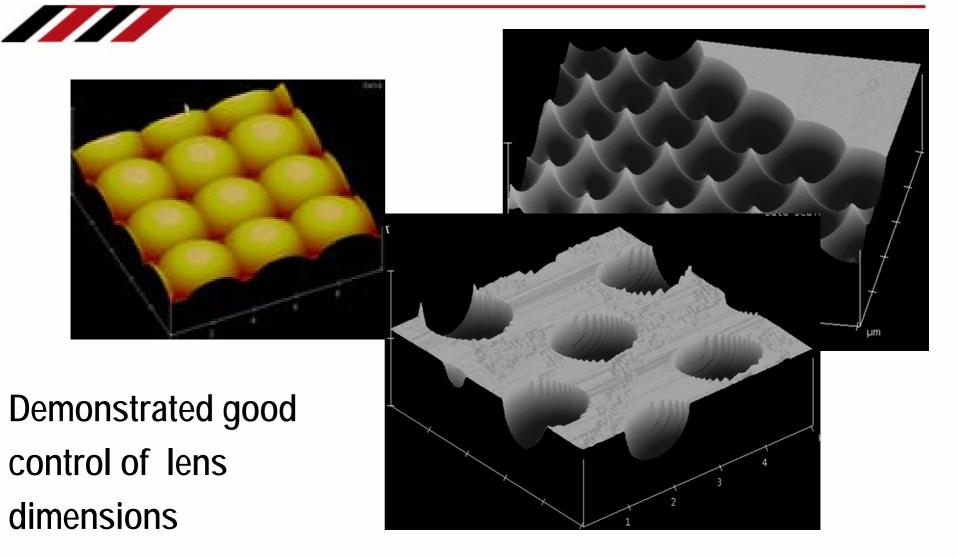


Second etch – defines lens width

3. Use wet etching of stripped quartz to modify lens shape



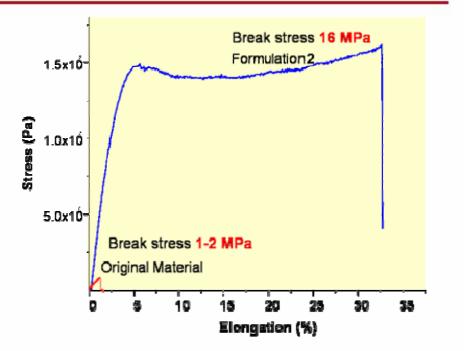
Grayscale Templates:





Imprint Material = Optical Object

- MII developed acrylate based functional materials for microlens
 - Index of refraction 1.4 1.5
 - pass photo darkening tests
 - thermal stability > 200 C
- Optimized mechanical and release properties
- Zero waste
 - 10 ml of material processes
 1000's 200 mm wafers

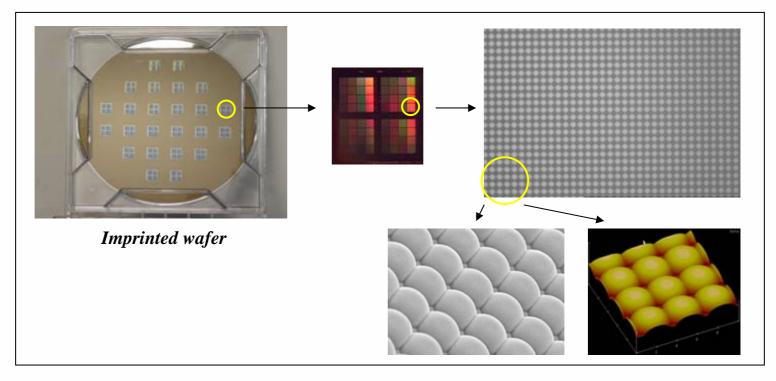






Micro-Lens Imprint Results

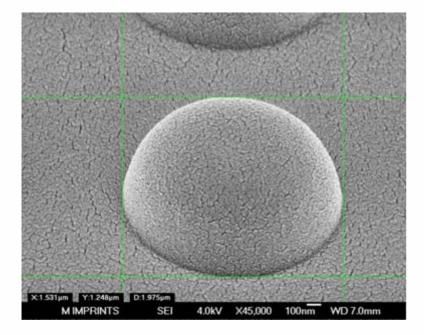
 Grayscale Template and Imprint

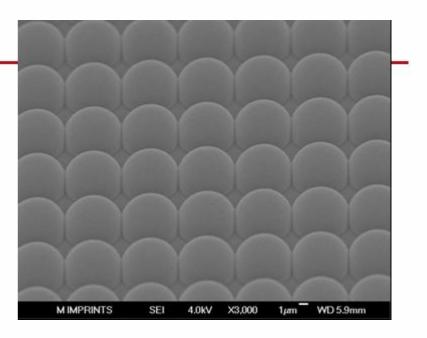


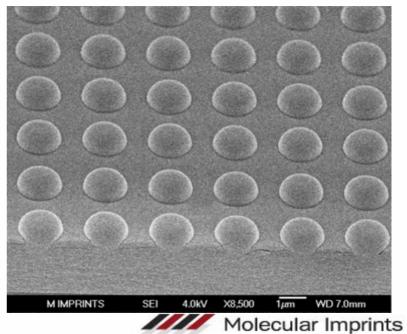


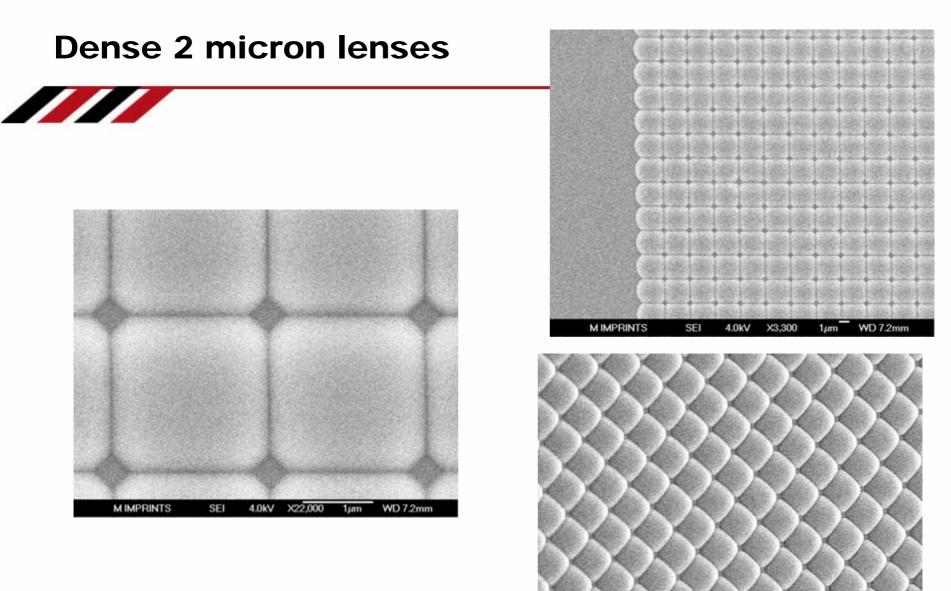
Isolated 1.5 micron lenses













1µm

WD 6.8mm

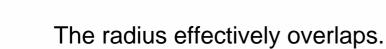
X4,500

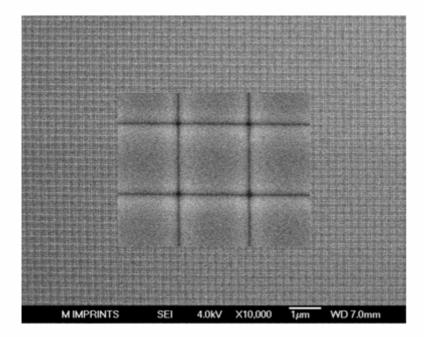
4.0kV

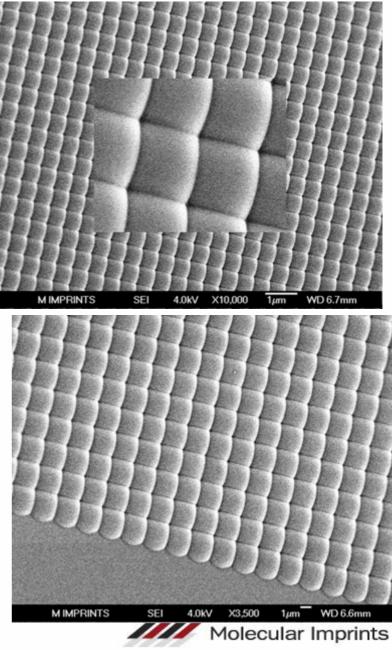
SEI

M IMPRINTS

Super dense 2 micron lenses







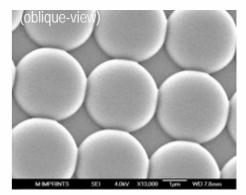
Micro-Optical Lens Arrays

Background: Added to a digital camera's CMOS/CCD image chip to improve optical collection efficiency Challenge: Patterning of high packing density lens arrays Experimental Results: will be presented by device manufacturer in the near future

Benefits of S-FIL

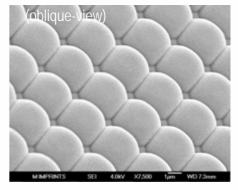
- S-FIL's 3-dimensional imprinting capability enables
 - Micro-lens array replication in a single step
 - No etching required
 - Higher micro-lens array packing density
 - Customized lens shapes
 - Imprinting using 'functional' materials (ie: optimized for a specific optical index of refraction)
- Enables improvement in optical collection efficiency

Imprinted array of micro-lenses



Imprinted array of micro-lenses

(high density packing)





Conclusion

Nano Imprint lithography is demonstrating to be a cost effective production lithography technology for sub 100nm and microns size patterns for different Industrial applications and with unique capabilities of multilayer and 3D Imprint of functional materials



